



# ES1AL THRU ES1JL

## SURFACE MOUNT SUPER FAST RECTIFIER

Reverse Voltage - 50 to 600 Volts Forward Current - 1.0 Ampere

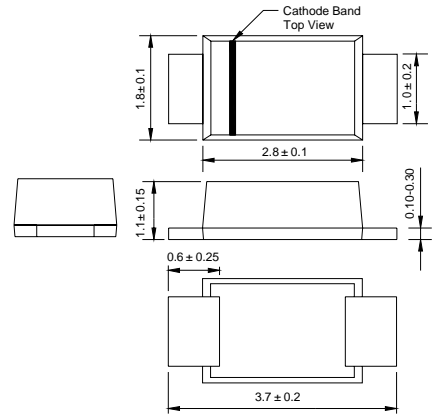
### FEATURES

Glass passivated device  
 Ideal for surface mounted applications  
 Low reverse leakage  
 Metallurgically bonded construction  
 High temperature soldering guaranteed:  
 260°C/10 seconds, 0.375" (9.5mm) lead length,  
 5 lbs. (2.3kg) tension

### MECHANICAL DATA

**Case:** JEDEC SOD-123FL molded plastic body over passivated chip  
**Terminals:** Plated axial leads, solderable per MIL-STD-750, Method 2026  
**Polarity:** Color band denotes cathode end  
**Mounting Position:** Any  
**Weight:** 0.0007 ounce, 0.02 grams

### SOD-123FL



Dimensions in millimeters

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.  
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	ES1AL	ES1BL	ES1CL	ES1DL	ES1EL	ES1GL	ES1JL	UNITS
		EA	EB	EC	ED	EE	EG	EJ	
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	150	200	300	400	600	VOLTS
Maximum RMS voltage	$V_{RMS}$	35	70	105	140	210	280	420	VOLTS
Maximum DC blocking voltage	$V_{DC}$	50	100	150	200	300	400	600	VOLTS
Maximum average forward rectified current at $T_A=100^\circ\text{C}$ (NOTE 1)	$I_{AV}$	1.0							Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	30.0							Amps
Maximum instantaneous forward voltage at 1.0A	$V_F$	0.95			1.25		1.7		Volts
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=125^\circ\text{C}$	$I_R$	5.0 100.0							$\mu\text{A}$
Maximum reverse recovery time (NOTE 1)	$t_{rr}$	35							ns
Typical junction capacitance (NOTE 2)	$C_J$	10							pF
Typical thermal resistance (NOTE 3)	$R_{\theta JA}$	85							K/W
Operating junction and storage temperature range	$T_J, T_{STG}$	-55 to +150							$^\circ\text{C}$

**Note:**  
 1. Measured with  $I_F=0.5\text{A}$ ,  $I_R=1\text{A}$ ,  $I_{rr}=0.25\text{A}$ .  
 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.  
 3. PCB mounted on 0.2\*0.2" (5.0\*5.0mm) copper pad area.



# RATINGS AND CHARACTERISTIC CURVES ES1AL THRU ES1JL

FIG. 1- FORWARD CURRENT DERATING CURVE

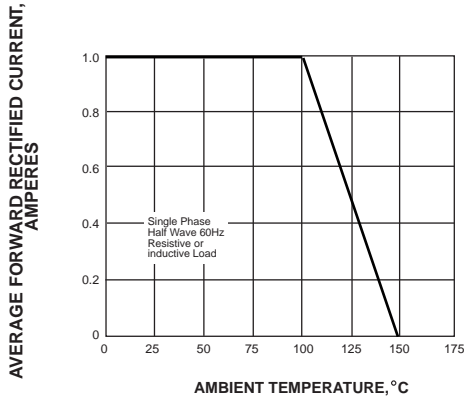


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

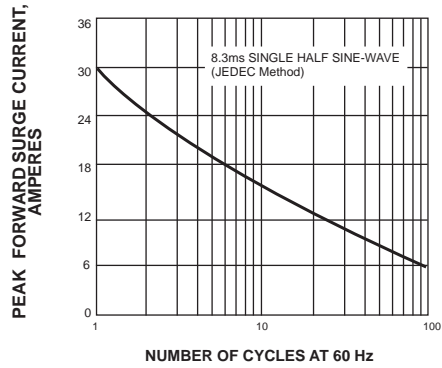


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

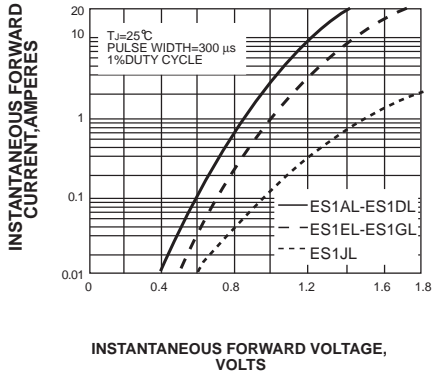


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

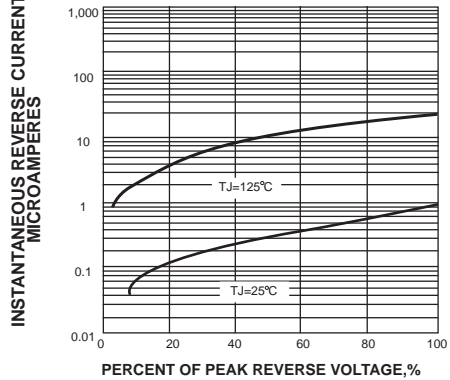


FIG. 5-TYPICAL JUNCTION CAPACITANCE

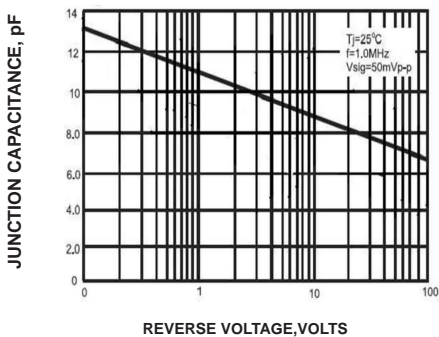
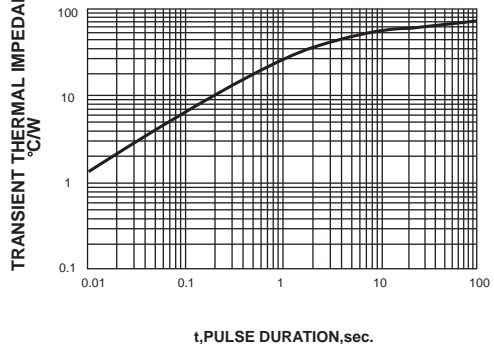


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



单击下面可查看定价，库存，交付和生命周期等信息

[>>ZG\(中鑫半导体\)](#)